Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Ceramic or glass

Overall Length:

Between 0.200 inches and 0.250 inches

Overall Diameter:

1.250 inches

Mounting Method:

Press fit

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

100.0 breakdown voltage, dc

Power Rating Per Characteristic:

2.5 watts small-signal input power, common-collector preset

Capacitance Rating In Picofarads:

1.2

Maximum Operating Tempurature Per Measurement Point:

75.0 degrees celsius ambient air

Test Data Document:

80063-sm-a-696588 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,

etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

2 case

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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